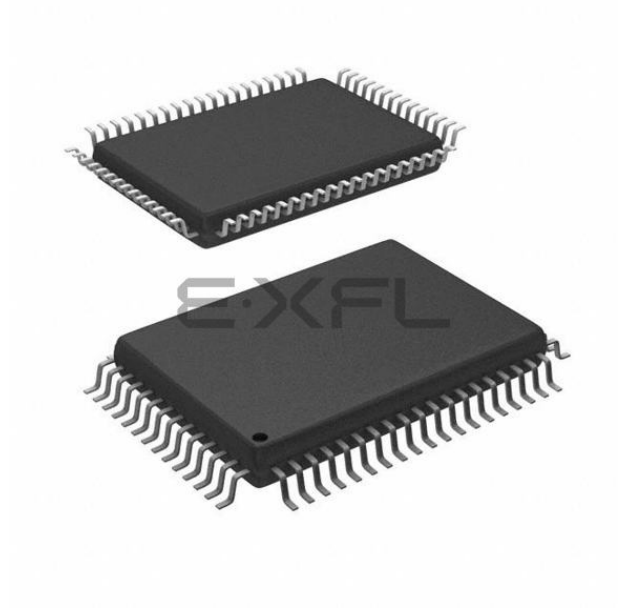


Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	F²MC-8L
Core Size	8-Bit
Speed	10MHz
Connectivity	EBI/EMI, Serial I/O, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	53
Program Memory Size	16KB (16K x 8)
Program Memory Type	Mask ROM
EEPROM Size	-
RAM Size	512 x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 6V
Data Converters	A/D 8x10b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-BQFP
Supplier Device Package	64-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb89635rpf-g-1494e1

FUJITSU MICROELECTRONICS
DATA SHEET

DS07-12531-4E

8-bit Proprietary Microcontroller

CMOS

F²MC-8L MB89630R Series

MB89635R/636R/637R/P637/PV630

■ OUTLINE

The MB89630R series has been developed as a general-purpose version of the F²MC*-8L family consisting of proprietary 8-bit, single-chip microcontrollers.

In addition to a compact instruction set, the microcontrollers contain a variety of peripheral functions such as dual-clock control system, five operating speed control stages, a UART, timers, a PWM timer, a serial interface, an A/D converter, an external interrupt, and a watch prescaler.

* : F²MC is the abbreviation for Fujitsu Flexible Microcontroller.

■ FEATURES

- High-speed operating capability at low voltage
- Minimum execution time: 0.4 µs@3.5 V, 0.8 µs@2.7 V
- F²MC-8L family CPU core

  Instruction set optimized for controllers
  - Multiplication and division instructions
  - 16-bit arithmetic operations
  - Test and branch instructions
  - Bit manipulation instructions, etc.

- Five types of timers
  8-bit PWM timer: 2 channels (Also usable as a reload timer)
  8-bit pulse-width count timer (Continuous measurement capable, applicable to remote control, etc.)
  16-bit timer/counter
  21-bit timebase timer

(Continued)

For the information for microcontroller supports, see the following web site.

http://edevice.fujitsu.com/micom/en-support/

2009.5

(Continued)

- UART
  CLK-synchronous/CLK-asynchronous data transfer capable (6, 7, and 8 bits)
- Serial interface
  Switchable transfer direction to allows communication with various equipment.
- 10-bit A/D converter
  Start by an external input capable
- External interrupt: 4 channels
  Four channels are independent and capable of wake-up from low-power consumption modes (with an edge detection function).
- Low-power consumption modes
  Stop mode (Oscillation stops to minimize the current consumption.)
  Sleep mode (The CPU stops to reduce the current consumption to approx. 1/3 of normal.)
  Subclock mode
  Watch mode
- Bus interface function
  With hold and ready function

(Continued)

Part number / Item	MB89635R	MB89636R	MB89637R	MB89P637	MB89PV630
External interrupt input	4 independent channels (edge selection, interrupt vector, source flag). Rising edge/falling edge selectable Used also for wake-up from stop/sleep mode. (Edge detection is also permitted in stop mode.)				
Standby mode	Sleep mode, stop mode, watch mode, and subclock mode				
Process	CMOS				
Operating voltage*	2.2 V to 6.0 V			2.7 V to 6.0 V	
EPROM for use					MBM27C256A-20CZ MBM27C256A-20TV

* : Varies with conditions such as the operating frequency. (See section "■ Electrical Characteristics.")
In the case of the MB89PV630, the voltage varies with the restrictions of the EPROM for use.

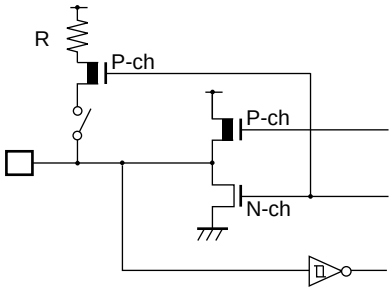
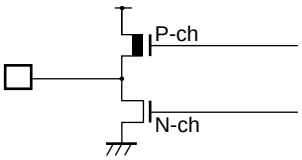
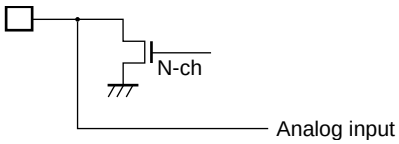
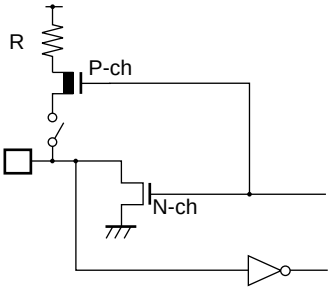
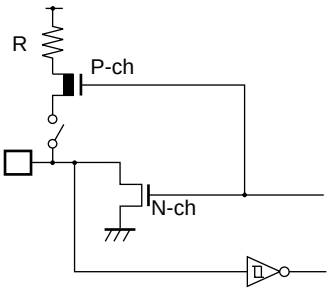
■ PACKAGE AND CORRESPONDING PRODUCTS

Package	MB89635R	MB89636R MB89637R	MB89P637	MB89PV630
DIP-64P-M01	○	○	○	×
FPT-64P-M06	○	○	○	×
FPT-64P-M23	○	○	×	×
MQP-64C-P01	×	×	×	○
MDP-64C-P02	×	×	×	○

○ : Available × : Not available

Note: For more information about each package, see section "■ Package Dimensions."

(Continued)

Type	Circuit	Remarks
G		• CMOS output • Hysteresis input • Pull-up resistor optional
H		CMOS output
I		Analog input
J		• CMOS input • Pull-up resistor optional
K		• Hysteresis input • Pull-up resistor optional

- **Programming procedure**

(1) Set the EPROM programmer to the MBM27C256A.

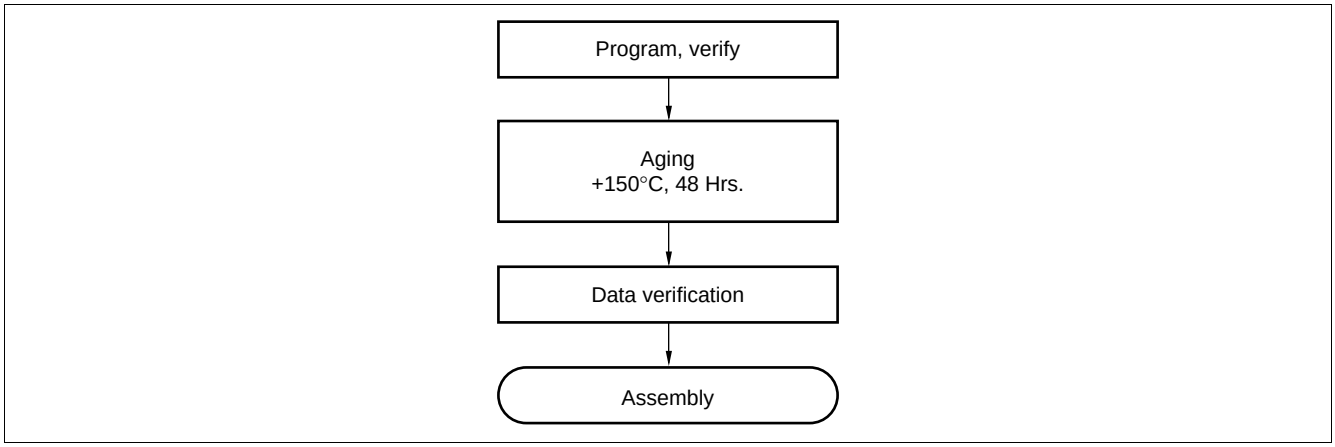
(2) Load program data into the EPROM programmer at 0007_H to $7FFF_H$. (Note that addresses 8000_H to $FFFF_H$ in the operating mode assign to 0000_H to $7FFF_H$ in EPROM mode).

(3) Load option data into addresses 0000_H to 0006_H of the EPROM programmer.
(For information about each corresponding option, see “8. OTPROM Option Bit Map”.)

(4) Program with the EPROM programmer.

4. Recommended Screening Conditions

High-temperature aging is recommended as the pre-assembly screening procedure for a product with a blanked OTPROM microcomputer program.



5. Programming Yield

All bits cannot be programmed at Fujitsu shipping test to a blanked OTPROM microcomputer, due to its nature. For this reason, a programming yield of 100% cannot be assured at all times.

6. OTPROM Option Bit Map

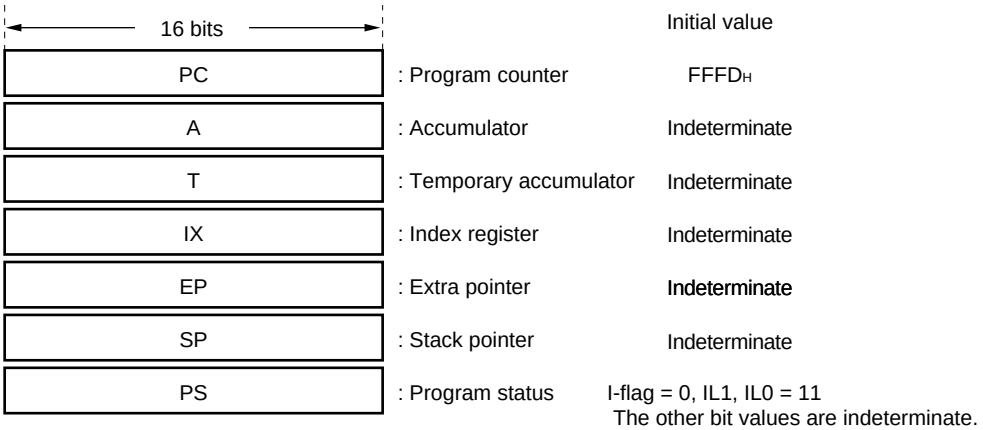
Address	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0000_H	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Single/dual-clock system 1: Dual clock 0: Single clock	Reset pin output 1: Yes 0: No	Power-on reset 1: Yes 0: No	Oscillation stabilization ($/F_{CH}$) 11: $2^{18}/F_{CH}$ 01: $2^{17}/F_{CH}$ 10: $2^{14}/F_{CH}$ 00: $2^4/F_{CH}$	
0001_H	P07 Pull-up 1: No 0: Yes	P06 Pull-up 1: No 0: Yes	P05 Pull-up 1: No 0: Yes	P04 Pull-up 1: No 0: Yes	P03 Pull-up 1: No 0: Yes	P02 Pull-up 1: No 0: Yes	P01 Pull-up 1: No 0: Yes	P00 Pull-up 1: No 0: Yes
0002_H	P17 Pull-up 1: No 0: Yes	P16 Pull-up 1: No 0: Yes	P15 Pull-up 1: No 0: Yes	P14 Pull-up 1: No 0: Yes	P13 Pull-up 1: No 0: Yes	P12 Pull-up 1: No 0: Yes	P11 Pull-up 1: No 0: Yes	P10 Pull-up 1: No 0: Yes
0003_H	P37 Pull-up 1: No 0: Yes	P36 Pull-up 1: No 0: Yes	P35 Pull-up 1: No 0: Yes	P34 Pull-up 1: No 0: Yes	P33 Pull-up 1: No 0: Yes	P32 Pull-up 1: No 0: Yes	P31 Pull-up 1: No 0: Yes	P30 Pull-up 1: No 0: Yes
0004_H	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	P43 Pull-up 1: No 0: Yes	P42 Pull-up 1: No 0: Yes	P41 Pull-up 1: No 0: Yes	P40 Pull-up 1: No 0: Yes
0005_H	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	P74 Pull-up 1: No 0: Yes	P73 Pull-up 1: No 0: Yes	P72 Pull-up 1: No 0: Yes	Vacancy Readable and writable	Vacancy Readable and writable
0006_H	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Vacancy Readable and writable	Reserved bit Readable and writable

Note: Each bit is set to ‘1’ as the initialized value.

2. Registers

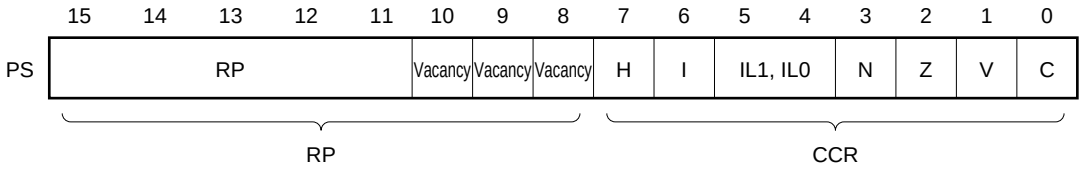
The F²MC-8L family has two types of registers; dedicated registers in the CPU and general-purpose registers in the memory. The following dedicated registers are provided:

Program counter (PC):	A 16-bit register for indicating the instruction storage positions
Accumulator (A):	A 16-bit temporary register for storing arithmetic operations, etc. When the instruction is an 8-bit data processing instruction, the lower byte is used.
Temporary accumulator (T):	A16-bit register which performs arithmetic operations with the accumulator When the instruction is an 8-bit data processing instruction, the lower byte is used.
Index register (IX):	A16-bit register for index modification
Extra pointer (EP):	A16-bit pointer for indicating a memory address
Stack pointer (SP):	A16-bit register for indicating a stack area
Program status (PS):	A16-bit register for storing a register pointer, a condition code



The PS can further be divided into higher 8 bits for use as a register bank pointer (RP) and the lower 8 bits for use as a condition code register (CCR). (See the diagram below.)

• Structure of the program status register



(Continued)

Address	Read/write	Register name	Register description
20H	(R/W)	ADC1	A/D converter control register 1
21H	(R/W)	ADC2	A/D converter control register 2
22H	(R/W)	ADDH	A/D converter data register (H)
23H	(R/W)	ADDL	A/D converter data register (L)
24H	(R/W)	EIC1	External interrupt control register 1
25H	(R/W)	EIC2	External interrupt control register 2
26H	Vacancy		
27H	Vacancy		
28H	(R/W)	CNTR1	PWM timer control register 1
29H	(R/W)	CNTR2	PWM timer control register 2
2AH	(R/W)	CNTR3	PWM timer control register 3
2BH	(W)	COMR1	PWM timer compare register 1
2CH	(W)	COMR2	PWM timer compare register 2
2DH	(R/W)	SMC	UART serial mode control register
2EH	(R/W)	SRC	UART serial rate control register
2FH	(R/W)	SSD	UART serial status/data register
30H	(R) (W)	SIDR SODR	UART serial input data control register UART serial output data control register
31H to 7BH	Vacancy		
7CH	(W)	ILR1	Interrupt level setting register 1
7DH	(W)	ILR2	Interrupt level setting register 2
7EH	(W)	ILR3	Interrupt level setting register 3
7FH	Vacancy		

Note: Do not use vacancies.

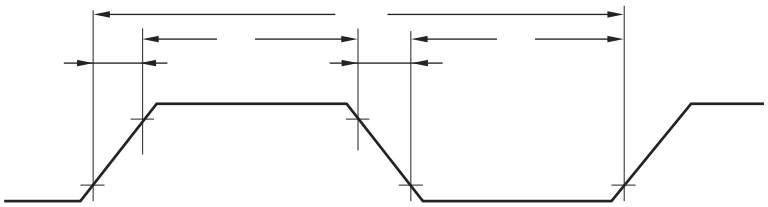
3. DC Characteristics

(AV_{CC} = V_{CC} = 5.0 V, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

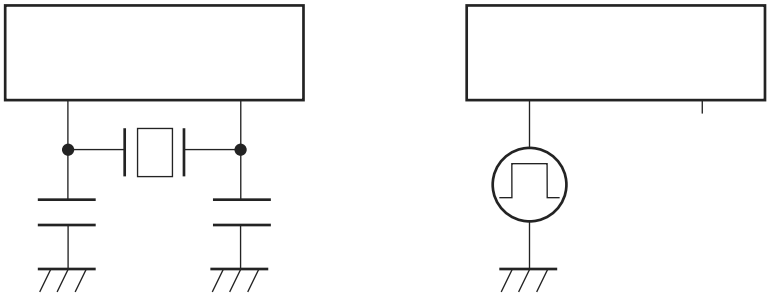
Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
"H" level input voltage	V_{IH1}	P00 to P07, P10 to P17, P22, P23, P31, P34, P37, P41, P43, P51 to P53	—	0.7 V_{CC}	—	V_{CC} + 0.3	V	P51 to P53 with pull-up resistor
	V_{IH2}	P51 to P53		0.7 V_{CC}	—	V_{SS} + 6.0	V	Without pull-up resistor
	V_{IHS}	$\overline{RST}$, MOD0, MOD1, P30, P32, P33, P35, P36, P40, P42,P50, P72 to P74		0.8 V_{CC}	—	V_{CC} + 0.3	V	P50 with pull-up resistor
	V_{IHS2}	P50, P70, P71		0.8 V_{CC}	—	V_{SS} + 6.0	V	Without pull-up resistor
"L" level input voltage	V_{IL}	P00 to P07, P10 to P17, P22, P23, P31, P34, P37, P41, P43		V_{SS} – 0.3	—	0.3 V_{CC}	V	
	V_{ILS}	P30, P32, P33, P35, P36, P40, P42, P50 to P53, P70 to P74, $\overline{RST}$, MOD0, MOD1		V_{SS} – 0.3	—	0.2 V_{CC}	V	
Open-drain output pin application voltage	V_D	P50 to P53		V_{SS} – 0.3	—	V_{SS} + 6.0	V	
"H" level output voltage	V_{OH}	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P43	I_{OH} = –2.0 mA	4.0	—	—	V	
"L" level output voltage	V_{OL}	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P43, P50 to P53, P60 to P67, $\overline{RST}$	I_{OL} = 4.0 mA	—	—	0.4	V	
Input leakage current (Hi-z output leakage current)	I_{LI}	P00 to P07, P10 to P17, P20 to P23, P30 to P37, P40 to P43, P50 to P53, P70 to P74, MOD0, MOD1	0.0 V < V_I < V_{CC}	—	—	±5	µA	Without pull-up resistor

(Continued)

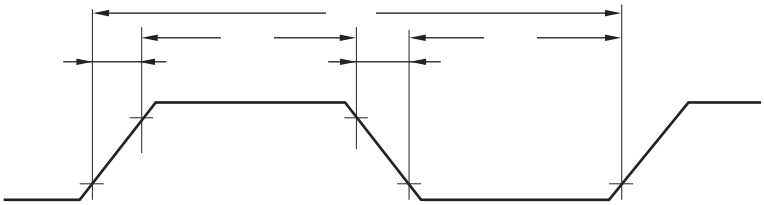
• **Main clock timing condition**



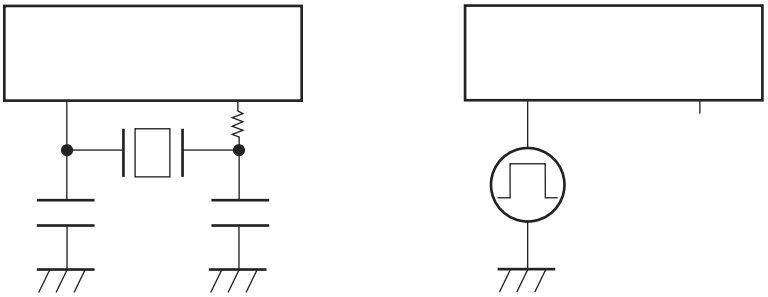
• **Main clock configurations**



• **Subclock timing condition**



• **Subclock configurations**



(4) Instruction Cycle

Parameter	Symbol	Value (typical)	Unit	Remarks
Instruction cycle (minimum execution time)	t_{inst}	$4/F_{CH}$, $8/F_{CH}$, $16/F_{CH}$, $64/F_{CH}$	µs	$(4/F_{CH})$ t_{inst} = 0.4 µs, operating at F_{CH} = 10 MHz
		$2/F_{CL}$	µs	t_{inst} = 61.036 µs, operating at F_{CL} = 32.768 kHz

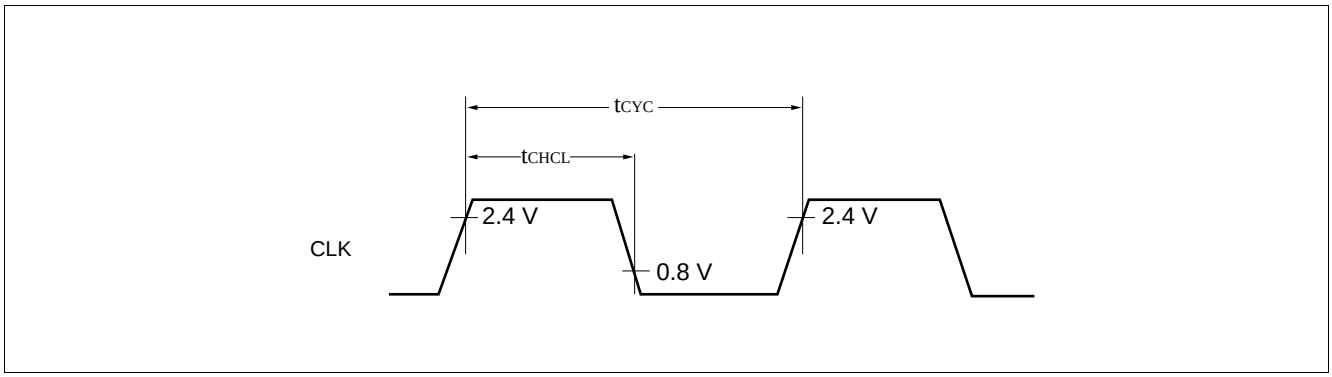
Note: Operating at 10 MHz, the cycle varies with the set execution time.

(5) Clock Output Timing

(V_{CC} = 5.0 V±10%, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Pin name	Condition	Value		Unit	Remarks
				Min.	Max.		
Cycle time	t_{CYC}	CLK	—	1/2 t_{inst}*	—	µs	
CLK ↑ → CLK ↓	t_{CHCL}	CLK		1/4 t_{inst}* – 70 ns	1/4 t_{inst}*	µs	

* : For information on t_{inst}, see “(4) Instruction Cycle”.



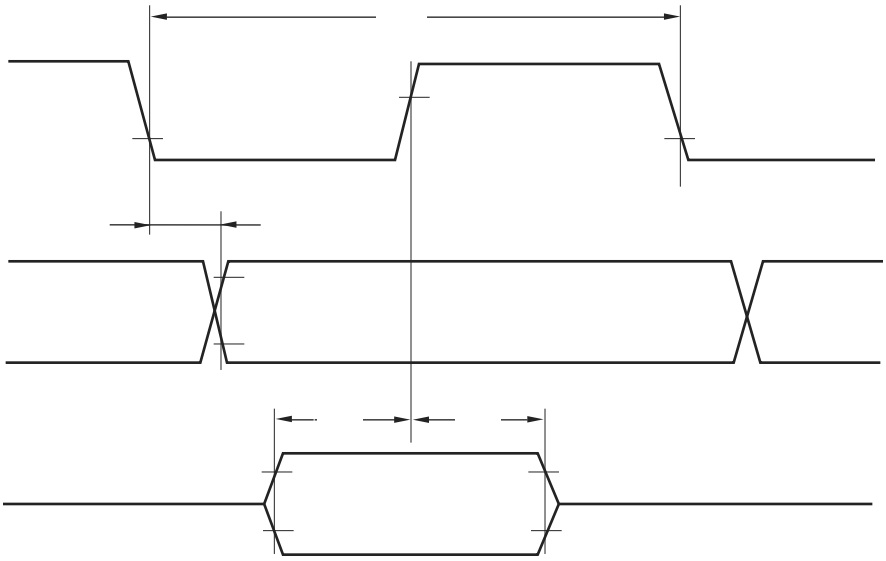
(9) Serial I/O Timing

(V_{CC} = 5.0 V±10%, F_{CH} = 10 MHz, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

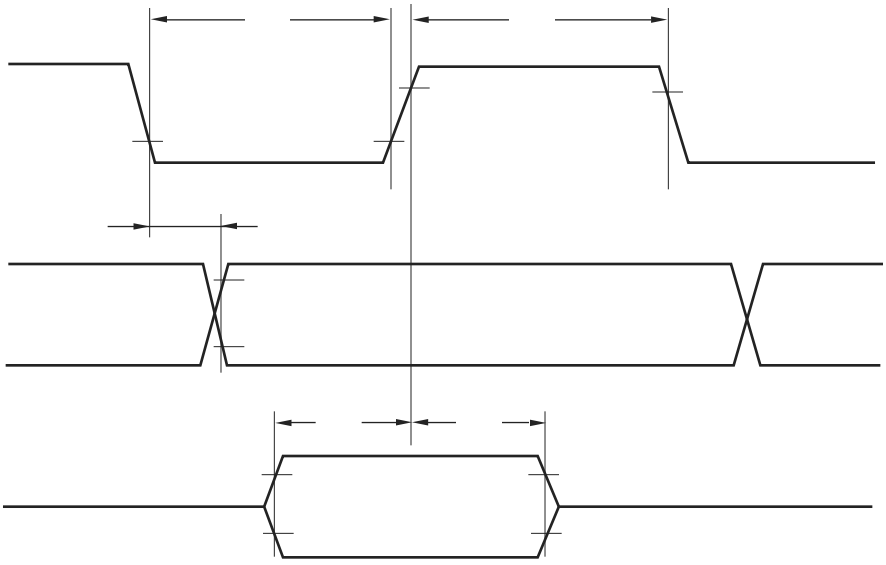
Parameter	Symbol	Pin name	Condition	Value		Unit	Remarks
				Min.	Max.		
Serial clock cycle time	t_{SCYC}	SCK1, UCK1, UCK2	Internal shift clock mode	2 t_{inst}*	—	µs	
SCK1 ↓ → SO1 time UCK1 ↓ → UO1 time UCK2 ↓ → UO2 time	t_{SLOV}	SCK1, SO1 UCK1, UO1 UCK2, UO2		–200	200	ns	
Valid SI1 → SCK1 ↑ Valid UI1 → UCK1 ↑ Valid UI2 → UCK2 ↑	t_{IVSH}	SI1, SCK1 UI1, UCK1 UI2, UCK2		1/2 t_{inst}*	—	µs	
SCK1 ↑ → valid SI1 hold time UCK1 ↑ → valid UI1 hold time UCK2 ↑ → valid UI2 hold time	t_{SHIX}	SCK1, SI1 UCK1, UI1 UCK2, UI2		1/2 t_{inst}*	—	µs	
Serial clock “H” pulse width	t_{SHSL}	SCK1, UCK1, UCK2	External shift clock mode	1 t_{inst}*	—	µs	
Serial clock “L” pulse width	t_{SLSH}	SCK1, UCK1, UCK2		1 t_{inst}*	—	µs	
SCK1 ↓ → SO1 time UCK1 ↓ → UO1 time UCK2 ↓ → UO2 time	t_{SLOV}	SCK1, SO1 UCK1, UO1 UCK2, UO2		0	200	ns	
Valid SI1 → SCK1 ↑ Valid UI1 → UCK1 ↑ Valid UI2 → UCK2 ↑	t_{IVSH}	SI1, SCK1 UI1, UCK1 UI2, UCK2		1/2 t_{inst}*	—	µs	
SCK1 ↓ → valid SI1 hold time UCK1 ↓ → valid UI1 hold time UCK2 ↓ → valid UI2 hold time	t_{SHIX}	SCK1, SI1 UCK1, UI1 UCK2, UI2		1/2 t_{inst}*	—	µs	

* : For information on t_{inst}, see “(4) Instruction Cycle”.

• **Internal shift clock mode**

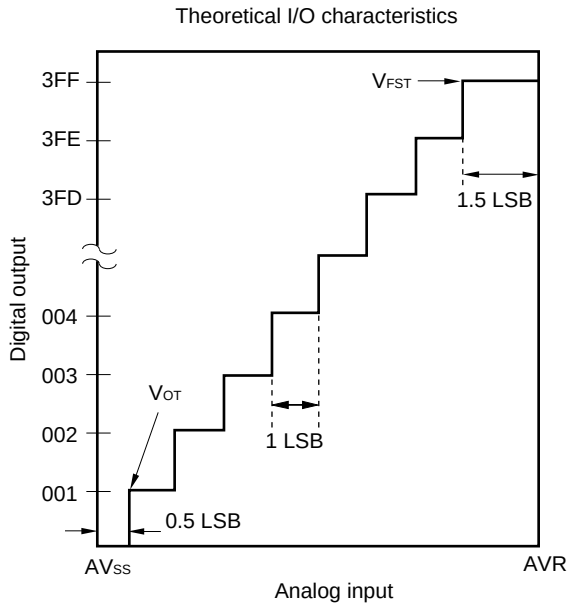


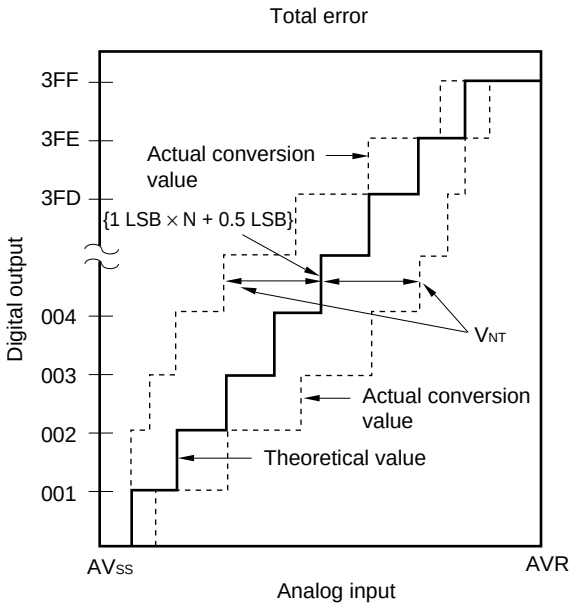
• **External shift clock mode**



6. A/D Converter Glossary

- Resolution
  Analog changes that are identifiable with the A/D converter
- Linearity error
  The deviation of the straight line connecting the zero transition point (“00 0000 0000” ↔ “00 0000 0001”) with the full-scale transition point (“11 1111 1110” ↔ “11 1111 1111”) from actual conversion characteristics
- Differential linearity error
  The deviation of input voltage needed to change the output code by 1 LSB from the theoretical value
- Total error (unit: LSB)
  The difference between theoretical and actual conversion values caused by the zero transition error, full-scale transition error, linearity error, quantization error, and noise





$$1\ \text{LSB} = \frac{V_{FST} - V_{OT}}{1022}\ (\text{V})$$

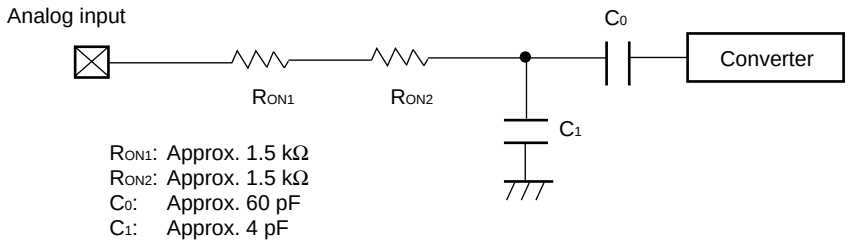
$$\text{Digital output N total error} = \frac{V_{NT} - \{1\ \text{LSB} \times N + 0.5\ \text{LSB}\}}{1\ \text{LSB}}$$

(Continued)

7. Notes on Using A/D Converter

- **Input impedance of the analog input pins**
  The output impedance of the external circuit for the analog input must satisfy the following conditions.
  If the output impedance of the external circuit is too high, an analog voltage sampling time might be insufficient (sampling time = 6 µs at 10 MHz oscillation.) Therefore, it is recommended to keep the output impedance of the external circuit below 10 kΩ.

- **Analog input circuit model**



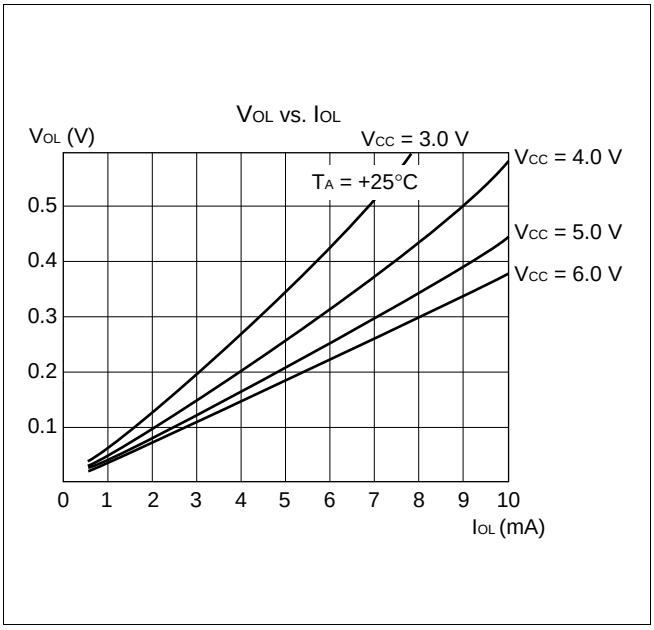
R_{ON1}: Approx. 1.5 kΩ
R_{ON2}: Approx. 1.5 kΩ
C_0: Approx. 60 pF
C_1: Approx. 4 pF

Note: The values mentioned here should be used as a guideline.

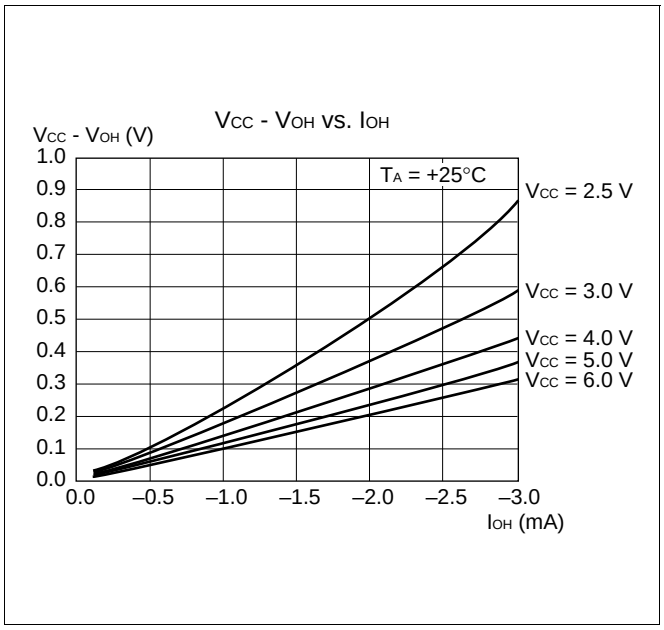
- **Error**
  The smaller the | AVR–AVss |, the greater the error would become relatively.

■ CHARACTERISTICS EXAMPLE

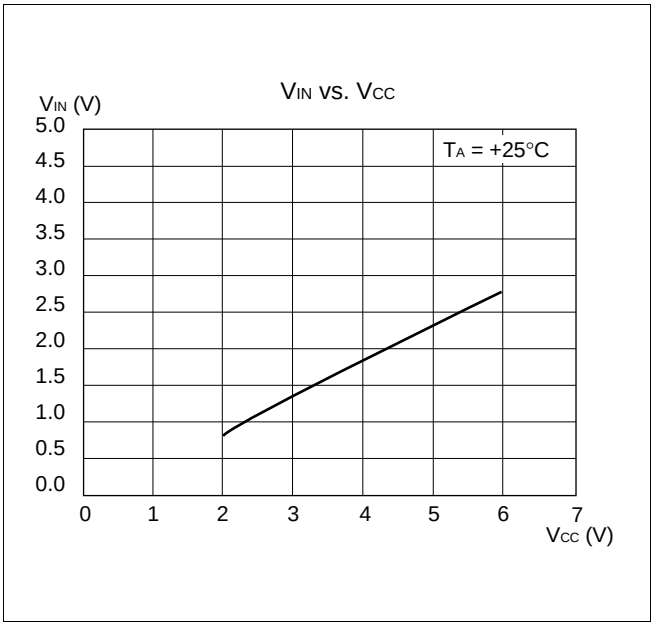
(1) “L” Level Output Voltage



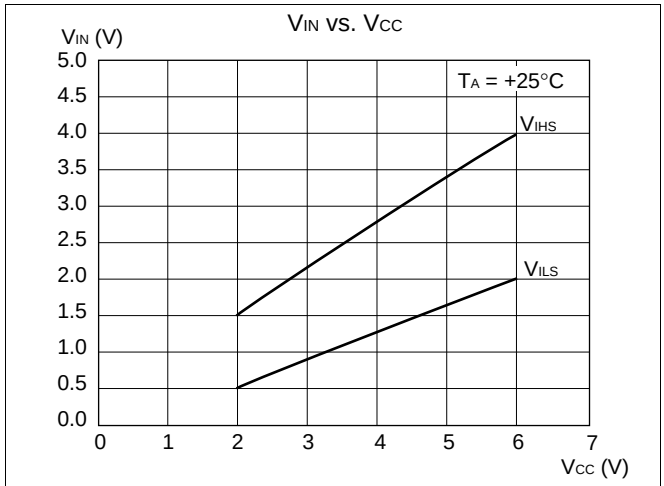
(2) “H” Level Output Voltage



(3) “H” Level Input Voltage/“L” Level Input Voltage (CMOS Input)



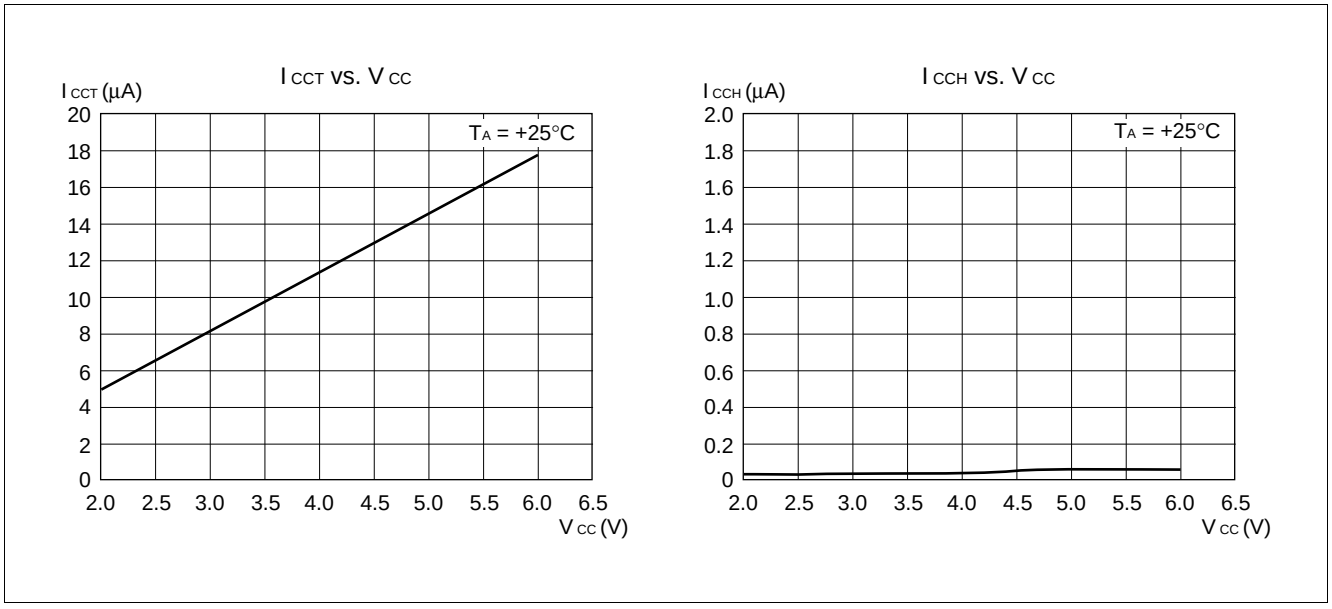
(4) “H” Level Input Voltage/“L” Level Input Voltage (Hysteresis Input)



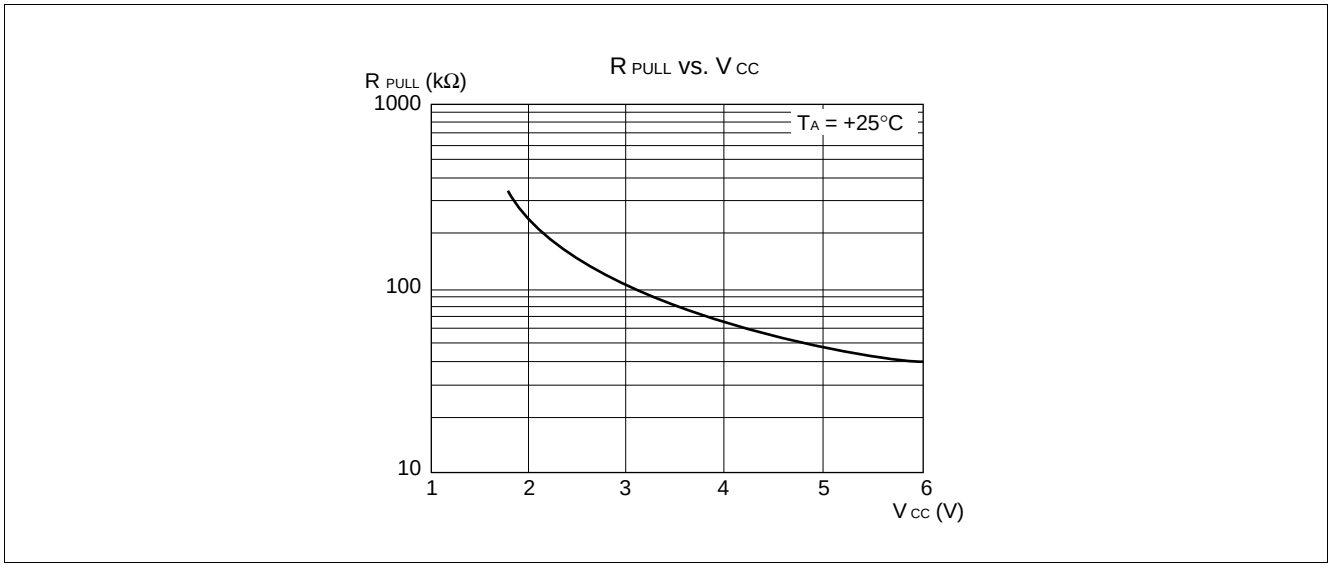
V_{IHS}: Threshold as the input voltage in hysteresis characteristics is set to “H” level

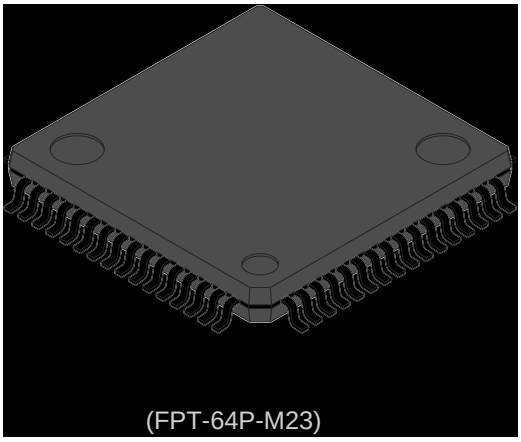
V_{ILS}: Threshold as the input voltage in hysteresis characteristics is set to “L” level

(Continued)

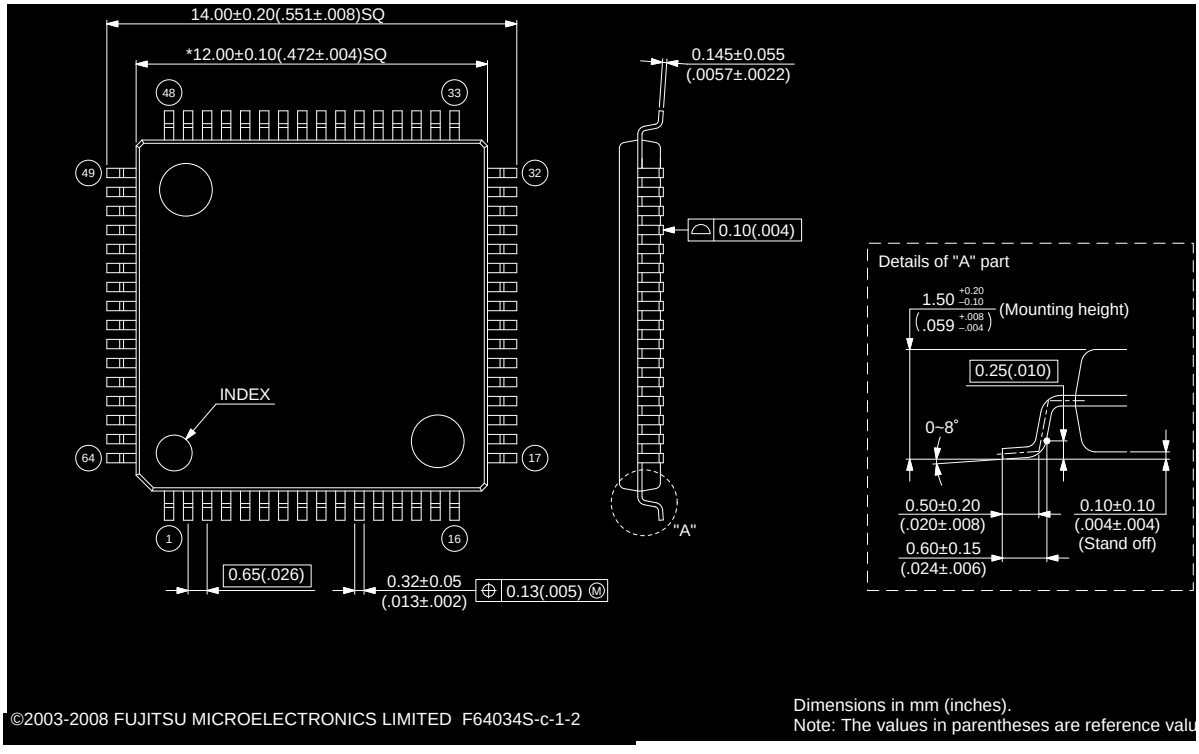


(6) Pull-up Resistance



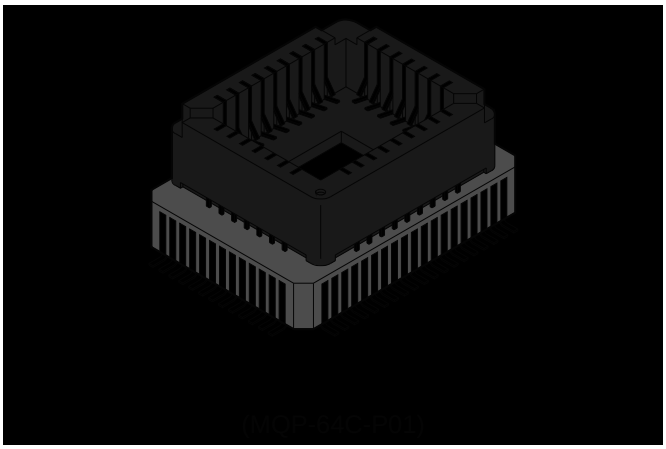


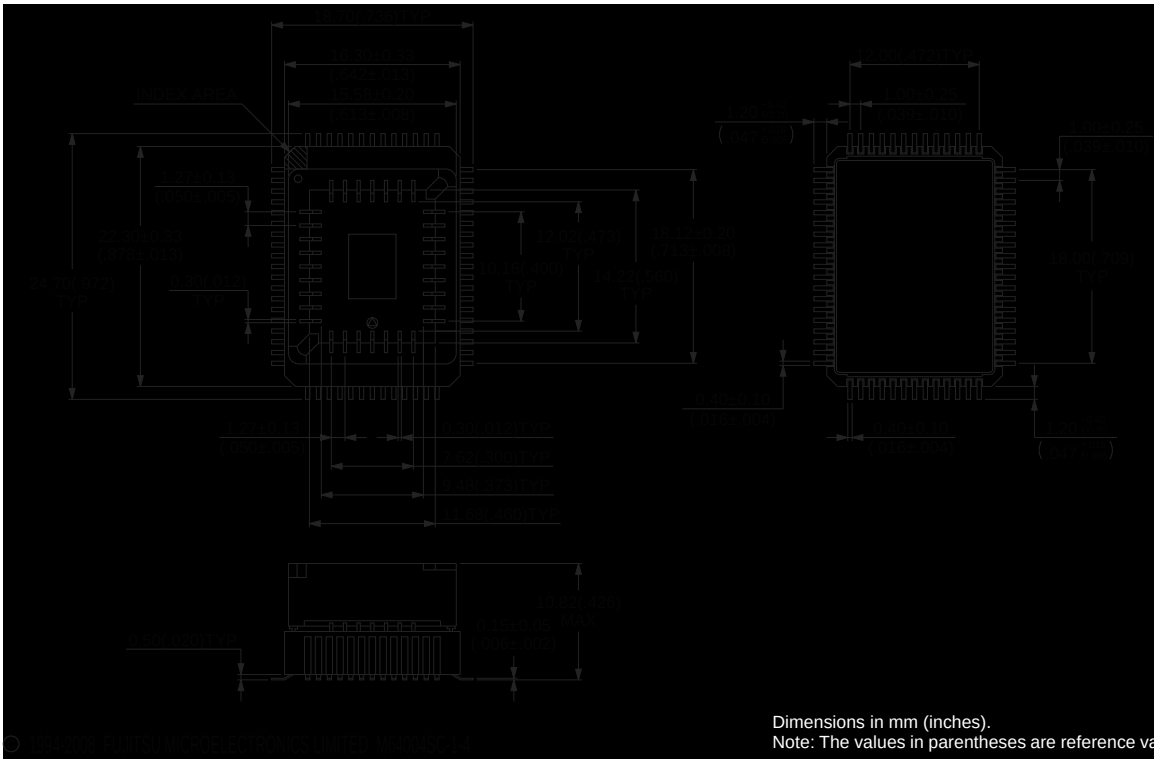
(FPT-64P-M23)



Please confirm the latest Package dimension by following URL.
http://edevice.fujitsu.com/package/en-search/

(Continued)





Please confirm the latest Package dimension by following URL.
http://edevice.fujitsu.com/package/en-search/

(Continued)

FUJITSU MICROELECTRONICS LIMITED

Shinjuku Dai-Ichi Seimei Bldg., 7-1, Nishishinjuku 2-chome,
Shinjuku-ku, Tokyo 163-0722, Japan
Tel: +81-3-5322-3329
http://jp.fujitsu.com/fml/en/

For further information please contact:

North and South America
FUJITSU MICROELECTRONICS AMERICA, INC.
1250 E. Arques Avenue, M/S 333
Sunnyvale, CA 94085-5401, U.S.A.
Tel: +1-408-737-5600 Fax: +1-408-737-5999
http://www.fma.fujitsu.com/

Europe
FUJITSU MICROELECTRONICS EUROPE GmbH
Pittlerstrasse 47, 63225 Langen, Germany
Tel: +49-6103-690-0 Fax: +49-6103-690-122
http://emea.fujitsu.com/microelectronics/

Korea
FUJITSU MICROELECTRONICS KOREA LTD.
206 Kosmo Tower Building, 1002 Daechi-Dong,
Gangnam-Gu, Seoul 135-280, Republic of Korea
Tel: +82-2-3484-7100 Fax: +82-2-3484-7111
http://kr.fujitsu.com/fmk/

Asia Pacific
FUJITSU MICROELECTRONICS ASIA PTE. LTD.
151 Lorong Chuan,
#05-08 New Tech Park 556741 Singapore
Tel : +65-6281-0770 Fax : +65-6281-0220
http://www.fmal.fujitsu.com/

FUJITSU MICROELECTRONICS SHANGHAI CO., LTD.
Rm. 3102, Bund Center, No.222 Yan An Road (E),
Shanghai 200002, China
Tel : +86-21-6146-3688 Fax : +86-21-6335-1605
http://cn.fujitsu.com/fmc/

FUJITSU MICROELECTRONICS PACIFIC ASIA LTD.
10/F., World Commerce Centre, 11 Canton Road,
Tsimshatsui, Kowloon, Hong Kong
Tel : +852-2377-0226 Fax : +852-2376-3269
http://cn.fujitsu.com/fmc/en/

Edited: Sales Promotion Department